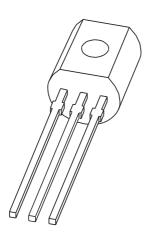
#### DISCRETE SEMICONDUCTORS

# DATA SHEET



## BC546; BC547; BC548 NPN general purpose transistors

Product specification Supersedes data of September 1994 File under Discrete Semiconductors, SC04 1997 Mar 04





### NPN general purpose transistors

BC546; BC547; BC548

#### **FEATURES**

- Low current (max. 100 mA)
- Low voltage (max. 65 V).

#### **APPLICATIONS**

• General purpose switching and amplification.

#### **DESCRIPTION**

NPN transistor in a TO-92; SOT54 plastic package. PNP complements: BC556, BC557 and BC558.

#### **PINNING**

PIN	DESCRIPTION		
1	emitter		
2	base		
3	collector		

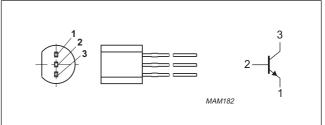


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BC546		_	80	V
	BC547		_	50	V
	BC548		_	30	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BC546		_	65	V
	BC547		_	45	V
	BC548		_	30	V
I <sub>CM</sub>	peak collector current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	_	500	mW
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V			
	BC546		110	450	
	BC547		110	800	
	BC548		110	800	
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V; f = 100 MHz	100	_	MHz

### NPN general purpose transistors

BC546; BC547; BC548

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter			
	BC546		_	80	V
	BC547		_	50	V
	BC548		_	30	V
V <sub>CEO</sub>	collector-emitter voltage	open base			
	BC546		_	65	V
	BC547		_	45	V
	BC548		_	30	V
V <sub>EBO</sub>	emitter-base voltage	open collector			
	BC546		_	6	V
	BC547		_	6	V
	BC548		_	5	V
I <sub>C</sub>	collector current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		_	200	mA
I <sub>BM</sub>	peak base current		_	200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	0.25	K/mW

#### Note

1. Transistor mounted on an FR4 printed-circuit board.

### NPN general purpose transistors

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#### **CHARACTERISTICS**

 $T_j$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V	_	_	15	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = 30 V; T <sub>j</sub> = 150 °C	_	_	5	μΑ
I <sub>EBO</sub>	emitter cut-off current	I <sub>C</sub> = 0; V <sub>EB</sub> = 5 V	_	_	100	nA
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 10 μA; V <sub>CE</sub> = 5 V;				
	BC546A; BC547A; BC548A	see Figs 2, 3 and 4	_	90	_	
	BC546B; BC547B; BC548B		_	150	_	
	BC547C; BC548C		_	270	_	
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V;				
	BC546A; BC547A; BC548A	see Figs 2, 3 and 4	110	180	220	
	BC546B; BC547B; BC548B		200	290	450	
	BC547C; BC548C		420	520	800	
	BC547; BC548		110	_	800	
	BC546		110	_	450	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	_	90	250	mV
		I <sub>C</sub> = 100 mA; I <sub>B</sub> = 5 mA	_	200	600	mV
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA; note 1	_	700	_	mV
		I <sub>C</sub> = 100 mA; I <sub>B</sub> = 5 mA; note 1	_	900	_	mV
V <sub>BE</sub>	base-emitter voltage	I <sub>C</sub> = 2 mA; V <sub>CE</sub> = 5 V; note 2	580	660	700	mV
		I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V	_	_	770	mV
C <sub>c</sub>	collector capacitance	I <sub>E</sub> = i <sub>e</sub> = 0; V <sub>CB</sub> = 10 V; f = 1 MHz	_	1.5	_	pF
C <sub>e</sub>	emitter capacitance	$I_C = I_c = 0$ ; $V_{EB} = 0.5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	11	_	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 10mA; V <sub>CE</sub> = 5 V; f = 100 MHz	100	_	_	MHz
F	noise figure	$I_C = 200 \mu A; V_{CE} = 5 V;$ $R_S = 2 k\Omega; f = 1 kHz; B = 200 Hz$	_	2	10	dB

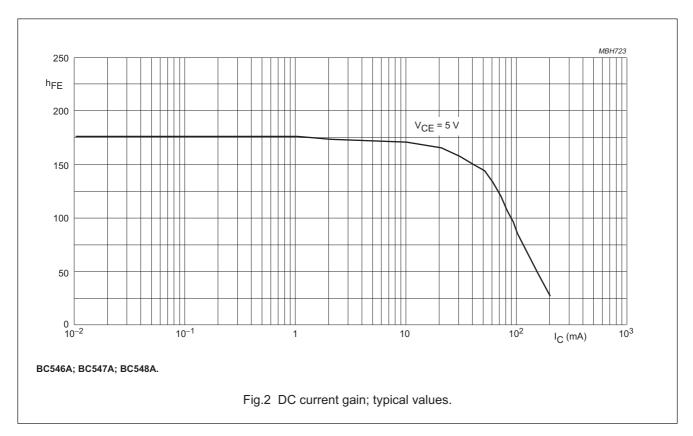
#### Notes

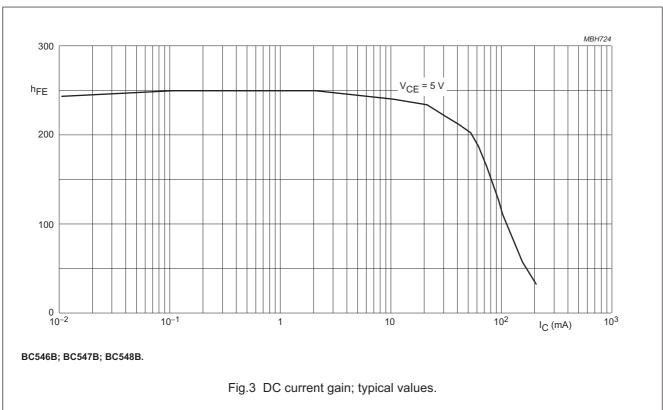
- 1.  $V_{\text{BEsat}}$  decreases by about 1.7 mV/K with increasing temperature.
- 2.  $V_{BE}$  decreases by about 2 mV/K with increasing temperature.

1997 Mar 04

### NPN general purpose transistors

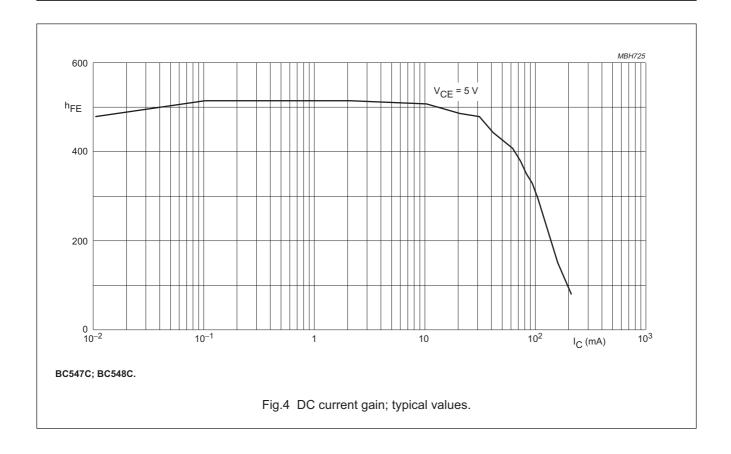
BC546; BC547; BC548





### NPN general purpose transistors

BC546; BC547; BC548



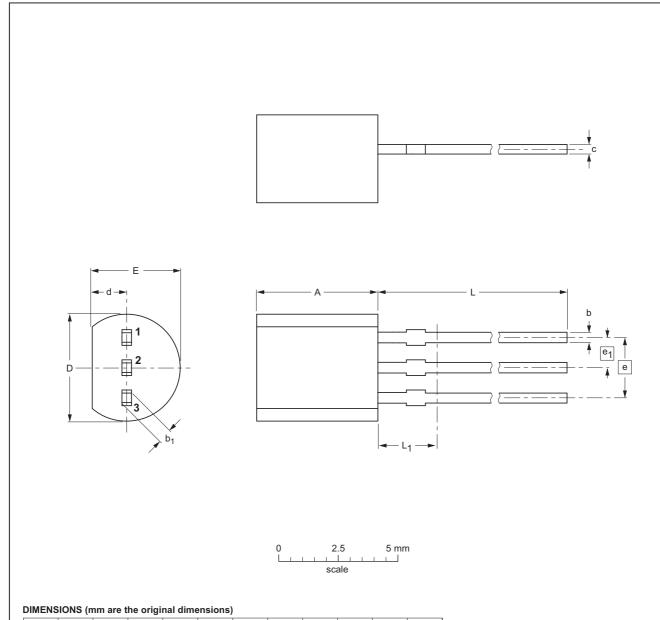
### NPN general purpose transistors

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#### **PACKAGE OUTLINE**

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



UNIT	Α	b	b <sub>1</sub>	С	D	d	E	е	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

#### Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1330E DATE	
SOT54		TO-92	SC-43		$ \  \   \bigoplus  \bigoplus$	97-02-28	

#### NPN general purpose transistors

BC546; BC547; BC548

#### **DEFINITIONS**

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

### NPN general purpose transistors

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**NOTES** 

### NPN general purpose transistors

BC546; BC547; BC548

**NOTES** 

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**NOTES** 

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